## The MEMS 5-in-1 Test Chips (Reference Materials 8096 and 8097)

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The MEMS 5-in-1 Reference Material (RM) is a single test chip with test structures from which material and dimensional properties are obtained using five documentary standard test methods (from which its name is derived). Companies can validate their use of the documentary standard test methods by comparing their inhouse measurements taken on the RM with the National Institute of Standards and Technology (NIST) measurements taken on the same test structures.

## **References:**

- Overview articles
  - J. Cassard, J. Geist, C. McGray, R.A. Allen, M. Afridi, B. Nablo, M. Gaitan, and D.G. Seiler, "The MEMS 5-in-1 Test Chips (Reference Materials 8096 and 8097)," *Frontiers of Characterization and Metrology for Nanoelectronics: 2013*, NIST, Gaithersburg, MD, March 25-28, 2013, pp. 179-182.
  - J. Cassard, J. Geist, M. Gaitan, and D. G. Seiler, "The MEMS 5-in-1 Reference Materials (RM 8096 and 8097)," *Proceedings of the 2012 International Conference on Microelectronic Test Structures*, ICMTS 2012, San Diego, CA, pp. 211-216, March 21, 2012.
- User's guide
  - J.M. Cassard, J. Geist, T.V. Vorburger, D.T. Read, M. Gaitan, and D.G. Seiler, "Standards Reference Materials: User's Guide for RM 8096 and 8097: The MEMS 5-in-1, 2013 Edition," NIST SP 260-177, February 2013 (http://dx.doi.org/10.6028/NIST.SP.260-177).
- Standards
  - SEMI MS4-0212, "Test Method for Young's Modulus Measurements of Thin, Reflecting Films Based on the Frequency of Beams in Resonance," February 2012. (Visit <u>http://www.semi.org</u> for ordering information.)
  - SEMI MS2-0212, "Test Method for Step Height Measurements of Thin Films," February 2012. (Visit <a href="http://www.semi.org">http://www.semi.org</a> for ordering information.)
  - ASTM E 2245-11, "Standard Test Method for Residual Strain Measurements of Thin, Reflecting Films Using an Optical Interferometer," December 2011. (Visit <u>http://www.astm.org</u> for ordering information.)
  - ASTM E 2246-11, "Standard Test Method for Strain Gradient Measurements of Thin, Reflecting Films Using an Optical Interferometer," January 2012. (Visit <u>http://www.astm.org</u> for ordering information.)
  - ASTM E 2244-11, "Standard Test Method for In-Plane Length Measurements of Thin, Reflecting Films Using an Optical Interferometer," December 2011. (Visit <u>http://www.astm.org</u> for ordering information.)
- Thickness articles
  - J.C. Marshall and P.T. Vernier, "Electro-physical technique for post-fabrication measurements of CMOS process layer thicknesses," *NIST J. Res.*, Vol. 112, No. 5, pp. 223-256, 2007.
  - J.C. Marshall, "New Optomechanical Technique for Measuring Layer Thickness in MEMS Processes," J. of Microelectromechanical Systems, Vol. 10, No. 1, pp. 153-157, March 2001.
- Fabrication
  - The RM 8096 chips were fabricated through MOSIS on the 1.5 μm On Semiconductor (formerly AMIS) CMOS process. The URL for the MOSIS website is <u>http://www.mosis.com</u>. The bulk-micromachining was performed at NIST.
  - The RM 8097 chips were fabricated at MEMSCAP using MUMPs-Plus! (PolyMUMPs with a backside etch). The URL for the MEMSCAP website is <u>http://www.memscap.com</u>.

2013 International Confirence on Frontiers of Characterization and Metrology for Nanoelectronics	The MEMS 5-in-1 Test Chips (Reference Materials 8096 and 8097) Janet Cassard (janet.cassard@nist.gov), Jon Geist (jon.geist@nist.gov), Craig McGray,† Richard Allen, Muhammad Afridi,‡ Brian Nablo, Michael Gaitan, and David Seiler Semiconductor and Dimensional Metrology Division, Physical Measurement Laboratory, NIST, †Modern Microsystems, Inc., and ‡Potomac Networks	United States" - Chris Muhlstein, ASTM
Test Structures	<ul> <li>MEMS 5-in-1 Reference Materials</li> <li>Image: Standard Reference Database 166</li> <li>MIST Standard Reference Database 166</li> <li>MEMS Calculator Web Pages validate industry measurements</li> <li>http://srdata.nist.gov/gateway/with keyword "MEMS Calculator"</li> <li>Documentary standards</li> <li>SEMI MS4-0212: Young's modulus MS2-0212: Step height</li> <li>ASTM (Led Development of First Standards) E2245-11: Residual strain E2246-11: Strain gradient E2244-11: In-plane length</li> <li>GMOS compatible MEMS test structures</li> <li>Fundamental measurement research</li> <li>Test structure design</li> <li>Test structure design</li> </ul>	Goal • Develop measurement methods to characterize MEMS devices for reliable manufacturing. Deliverables • R&D focused on - Test structure measurements - Measurement methods • Scientific publications • Documentary standards • Standard Reference Database • Reference Materials Customers & Collaborators • MEMS designers • Test equipment manufacturers • IC and MEMS foundries & services • Industry standards organizations

